19-3857; Rev 0; 11/06

MAX2022 Evaluation Kit

Evaluates: MAX2022

General Description

The MAX2022 evaluation kit (EV kit) simplifies the evaluation of the MAX2022 direct upconversion (downconversion) quadrature modulator (demodulator) designed for UMTS/WCDMA, cdma2000®, DCS/PCS, and WiMAX℠ base-station applications. It is fully assembled and tested at the factory. Standard 50Ω SMA connectors are included on the EV kit's input and output ports to allow quick and easy evaluation on the test bench using RF test equipment.

This document provides a list of test equipment required to evaluate the device, a straight-forward test procedure to verify functionality, a description of the EV kit circuit, the circuit schematic, a bill of materials (BOM) for the kit, and artwork for each layer of the PCB.

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Features

- **Fully Assembled and Tested**
- **50Ω SMA Connectors on Input and Output Ports**
- **1500MHz to 2500MHz RF Range**
- **High-Linearity and Low-Noise Performance**
- **Broadband Baseband Input/Output**
- **DC-Coupled Input Provides for Direct DAC/ADC Interface**

Ordering Information

PART	TEMP RANGE	IC PACKAGE
MAX2022EVKIT	-40°C to +85°C	36 QFN-EP*

**EP = Exposed paddle.*

Component List

DESIGNATION	QTY	DESCRIPTION
C1, C3, C6, C7, C10, C13	6	22pF ±5%, 50V C0G ceramic capacitors (0402) Murata GRM1555C1H220J
C2, C5, C8, C11, C12	5	0.1µF ±10%, 16V X7R ceramic capacitors (0603) Murata GRM188R71C104K
C4	0	Not installed
C9	1	1.2pF ±0.1pF, 50V C0G ceramic capacitor (0402) Murata GRM1555C1H1R2B
J1–J6	6	PCB edge-mount SMA RF connectors (flat-tab launch) Johnson 142-0741-856
R1	1	432Ω ±1% resistor (0402)
R2	1	562Ω ±1% resistor (0402)
R3	1	301Ω ±1% resistor (0402)
R4, R7, R8, R11	4	0Ω resistors (0402)

DESIGNATION	QTY	DESCRIPTION
R5, R6, R9, R10, R12–R15	0	Not installed
TP1	1	Large test point for 0.062in PCB (red) Mouser 151-107-RC or equivalent
TP2	1	Large test point for 0.062in PCB (black) Mouser 151-103-RC or equivalent
TP3	0	Not installed
U1	1	Active-mixer IC (6mm x 6mm, 36-pin QFN-EP) Maxim MAX2022ETX+ **NOTE: U1 HAS AN EXPOSED PADDLE CONDUCTOR THAT REQUIRES IT TO BE SOLDER ATTACHED TO A GROUNDED PAD ON THE CIRCUIT BOARD TO ENSURE A PROPER ELECTRICAL/THERMAL DESIGN.**

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

Component Suppliers

SUPPLIER	PHONE	WEBSITE
Johnson	507-833-8822	www.johnsoncomponents.com
M/A-Com	1-800-366-2266	www.macom.com
Murata	770-436-1300	www.murata.com

Note: *Indicate that you are using the MAX2022 when contacting these component suppliers.*

Quick Start

The MAX2022 EV kit is fully assembled and factory tested. Follow the instructions in the *Connections and Setup* section for proper device evaluation as an upconverter.

Test Equipment Required

This section lists the recommended test equipment to verify the operation of the MAX2022 as an upconverter. It is intended as a guide only, and substitutions may be possible.

- One DC supply capable of delivering +5.0V and 350mA
- One low-noise RF signal generator capable of delivering 10dBm of output power in the 1GHz to 3GHz frequency range (i.e., HP 8648)
- One I/Q generator capable of producing two differential 1MHz sine waves, 90° out-of-phase with each other, with a 200mV$_{P-P}$ differential amplitude
- One quad-channel oscilloscope with a 100MHz minimum bandwidth
- Low-capacitance oscilloscope probes
- One RF spectrum analyzer with a 100kHz to 3GHz frequency range (HP 8561E)
- One RF power meter (HP 437B)
- One power sensor (HP 8482A)

Connections and Setup

This section provides a step-by-step guide to testing the basic functionality of the EV kit as an upconverter. As a general precaution to prevent damaging the outputs by driving high VSWR loads, do not turn on DC power or RF signal generators until all connections are made.

This upconverter procedure is general to operation with an I/Q baseband input signal at 1MHz. Choose the test frequency based on the particular system's frequency plan and adjust the following procedure accordingly. See Figure 2 for the test setup diagram.

1) Calibrate the power meter. For safety margin, use a power sensor rated to at least +20dBm, or use padding to protect the power head as necessary.
2) Connect a 3dB pad to the DUT end of the RF signal generators' SMA cable. This padding improves VSWR and reduces the errors due to mismatch.
3) Use the power meter to set the RF signal generators according to the following:
   - LO signal source: 0dBm into DUT at 2140MHz (this will be approximately 3dBm before the 3dB pad).

   Use an oscilloscope to set the baseband I/Q differential inputs to the following:
   - I/Q signal source: 109mV$_{P-P}$ differential into I+/I- and Q+/Q- input ports at 1MHz. Note that the differential I+/I- and Q+/Q- source impedance needs to be 50Ω.
4) Disable the signal generator outputs.
5) Connect the I/Q source to the differential I/Q ports.
6) Connect the LO source to the EV kit LO input.
7) Measure the loss in the 3dB pad and cable that will be connected to the RF port. Losses are frequency dependent, so test this at 2140MHz (the RF frequency). Use this loss as an offset in all output power/gain calculations.
8) Connect this 3dB pad to the EV kit's RF port connector and connect a cable from the pad to the spectrum analyzer.
9) Set the DC supply to +5.0V, and set a current limit around 350mA, if possible. Disable the output voltage and connect the supply to the EV kit (through an ammeter, if desired). Enable the supply. Readjust the supply to get +5.0V at the EV kit. A voltage drop occurs across the ammeter when the device is drawing current.
10) Enable the LO and the I/Q sources.

Testing the Direct Upconverter

Adjust the center and span of the spectrum analyzer to 2140MHz and 5MHz, respectively. The LO leakage appears at 2140MHz and there are two sidebands at 2139MHz and 2141MHz (LSB and USB). One of the sidebands is the selected RF signal, while the second is the image. Depending on whether the Q channel is 90 degrees advanced or 90 degrees delayed from the I channel determines which sideband is selected and which is rejected. Note that the sideband suppression is about 45dB typical down from the desired sideband.

The desired sideband power level should be approximately -23.5dBm (-20.5dBm output power including 3dB pad loss). Phase and amplitude differences at the I and Q inputs result in degradation of the sideband suppression. Note that the spectrum analyzer's uncalibrated absolute magnitude accuracy is typically no better than ±1dB.

Detailed Description

The MAX2022 is designed for upconverting (downconverting) to (from) a 1500MHz to 2500MHz RF from (to) baseband. Applications include single- and multicarrier 1800MHz to 2200MHz UMTS/WCDMA, cdma2000, DCS/PCS, and WiMAX base stations. Direct upconversion (downconversion) architectures are advantageous since they significantly reduce transmitter (receiver) cost, part count, and power consumption compared to traditional heterodyne conversion systems.

The MAX2022 integrates internal baluns, an LO buffer, a phase splitter, two LO driver amplifiers, two matched double-balanced passive mixers, and a wideband quadrature combiner. Precision matching between the in-phase and quadrature channels, and highly linear mixers achieve excellent dynamic range, ACLR, 1dB compression point, along with LO and sideband suppression, making it ideal for 4-carrier W-CDMA/UMTS operation.

The MAX2022 EV kit circuit allows for thorough analysis and a simple design-in.

Supply-Decoupling Capacitors

The MAX2022 has several RF processing stages that use the various V_{CC} pins. While they have on-chip decoupling, off-chip interaction between them may degrade gain, linearity, carrier suppression, and output power. Proper voltage-supply bypassing is essential for high-frequency circuit stability.

C1, C6, C7, C10, and C13 are 22pF supply-decoupling capacitors used to filter high-frequency noise. C2, C5, C8, C11, and C12 are larger 0.1µF capacitors used for filtering lower-frequency noise on the supply.

DC-Blocking Capacitors

The MAX2022 has internal baluns at the RF output and LO input. These inputs have almost 0Ω resistance at DC, and so DC-blocking capacitors C3 and C9 are used to prevent any external bias from being shunted directly to ground.

LO Bias

The bias current for the integrated LO buffer is set with resistor R1 (432Ω ±1%). Resistors R2 (562Ω ±1%) and R3 (301Ω ±1%) set the bias currents for the LO driver amplifiers. Increasing the value of R1, R2, and R3 reduces the current, but the device will operate at reduced performance levels. Doubling the values of R1, R2, and R3 reduces the total current to approximately 166mA, but the OIP3 degrades by approximately 4.5dB.

IF Bias

When desired, a common-mode voltage can be injected onto the BB input lines through TP3 on the EV kit. To enable this feature, the proper value of resistors R5, R6, R9, R10, and R12–R15 need to be installed. Resistors R15/R14 and R13/R12 form voltage-dividers, while R5, R6, R9, and R10 are large-value bias injection resistors. See Figure 3 for EV kit schematic details.

External Diplexer

LO leakage at the RF port can be nulled to a level less than -80dBm by introducing DC offsets at the I and Q ports. However, this null at the RF port can be compromised by an improperly terminated I/Q IF interface. Care must be taken to match the I/Q ports to the driving DAC circuitry. Without matching, the LO's second-order ($2f_{LO}$) term may leak back into the modulator's I/Q input port where it can mix with the internal LO signal to produce additional LO leakage at the RF output. This leakage effectively counteracts against the LO nulling. In addition, the LO signal reflected at the I/Q IF port produces a residual DC term that can disturb the nulling condition.

As shown in Figure 1, providing an RC termination on each of the I+, I-, Q+, Q- ports reduces the amount of LO leakage present at the RF port under varying temperature, LO frequency, and baseband drive conditions. Note that the resistor value is chosen to be 100Ω with a corner frequency 1 / (2πRC) selected to adequately filter the f_{LO} and $2f_{LO}$ leakage, yet not affecting the flatness of the baseband response at the highest baseband frequency. The common-mode f_{LO} and $2f_{LO}$ signals at I+/I- and Q+/Q- effectively see the RC networks and thus become terminated in 50Ω (R/2). The RC network provides a path for absorbing the $2f_{LO}$ and f_{LO} leakage, while the inductor provides high impedance at f_{LO} and $2f_{LO}$ to help the diplexing process.

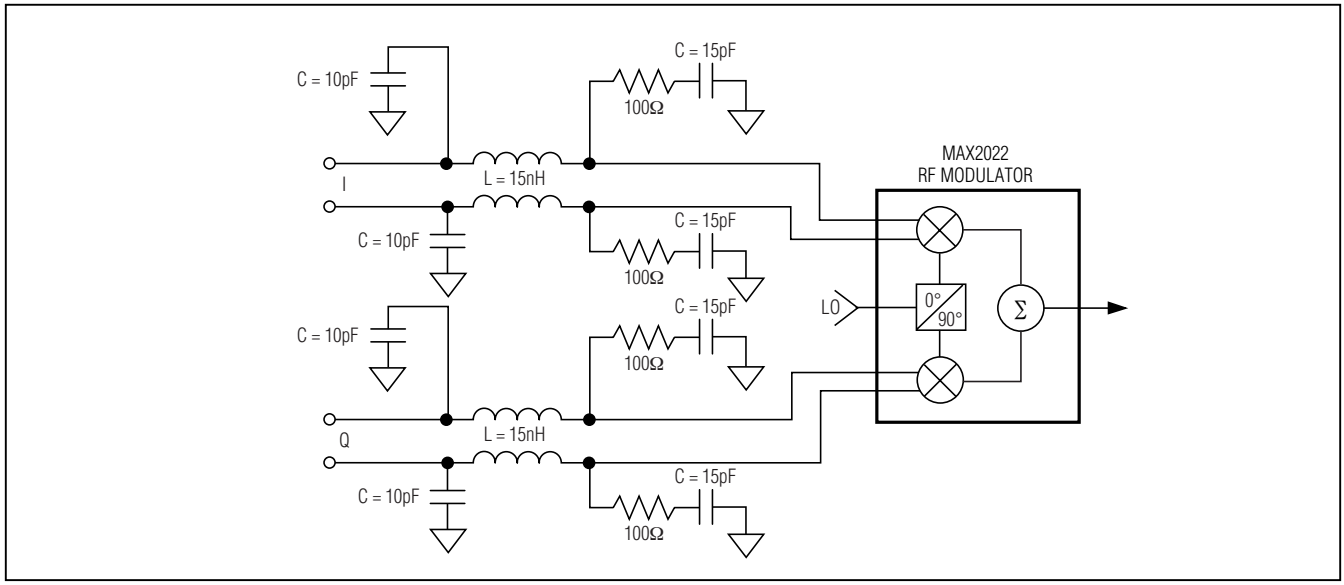


Figure 1. Diplexer Network

Layout Considerations

The MAX2022 evaluation board can be a guide for your board layout. Pay close attention to thermal design and close placement of components to the IC. The MAX2022's package exposed paddle (EP) conducts heat from the device and provides a low-impedance electrical connection to the ground plane. The EP must be attached to the PCB ground plane with a low thermal and electrical impedance contact. Ideally, this is achieved by soldering the backside of the package directly to a top metal ground plane on the PCB. Alternatively, the EP can be connected to an internal or bottom-side ground plane using an array of plated vias directly below the EP. The MAX2022 EV kit uses nine evenly spaced 0.016in-diameter, plated through holes to connect the EP to the lower ground planes.

Depending on the ground plane spacing, large surface-mount pads in the IF path may need to have the ground plane relieved under them to reduce parasitic shunt capacitance.

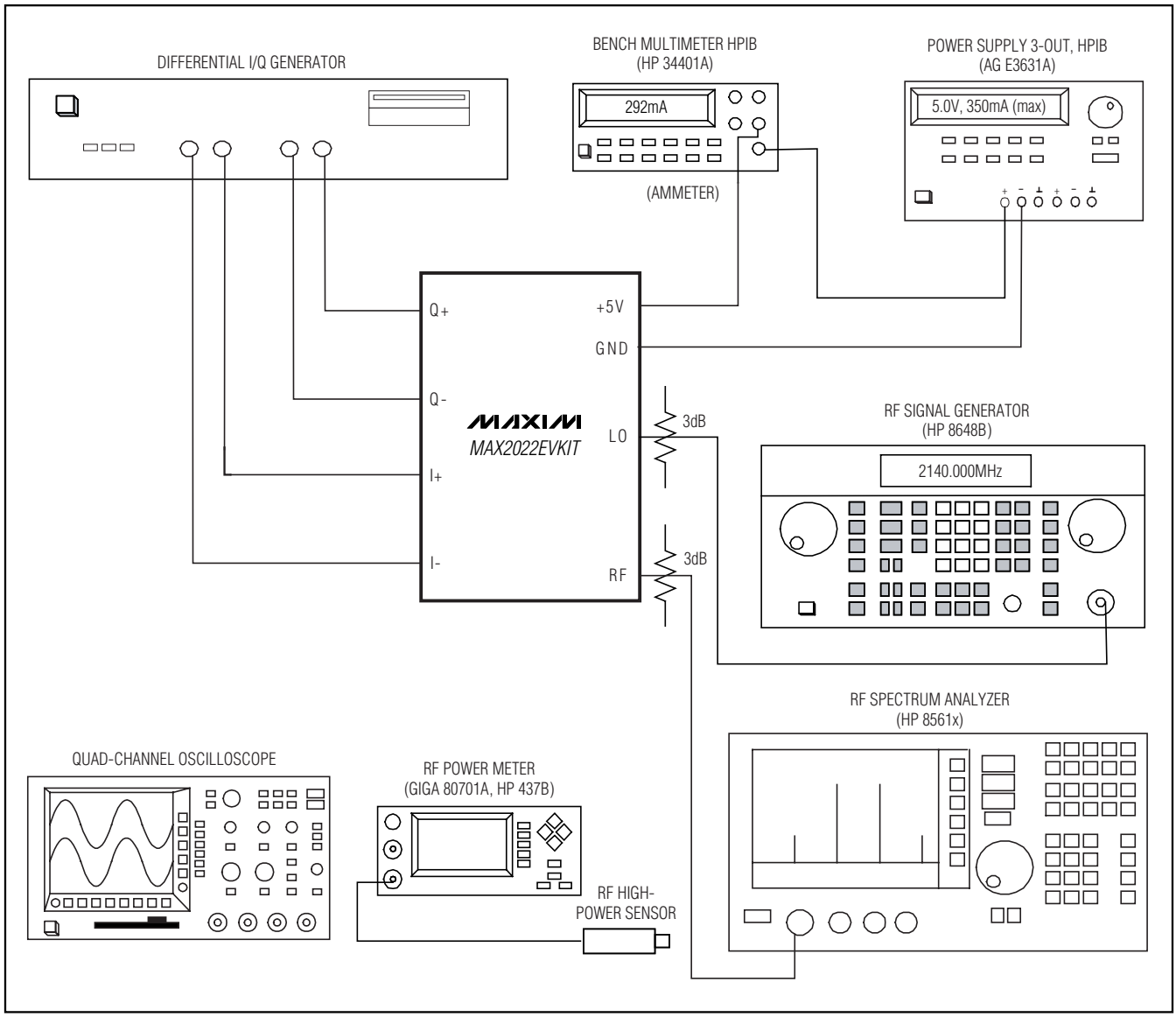


Figure 2. Test Setup Diagram

MAX2022 Evaluation Kit

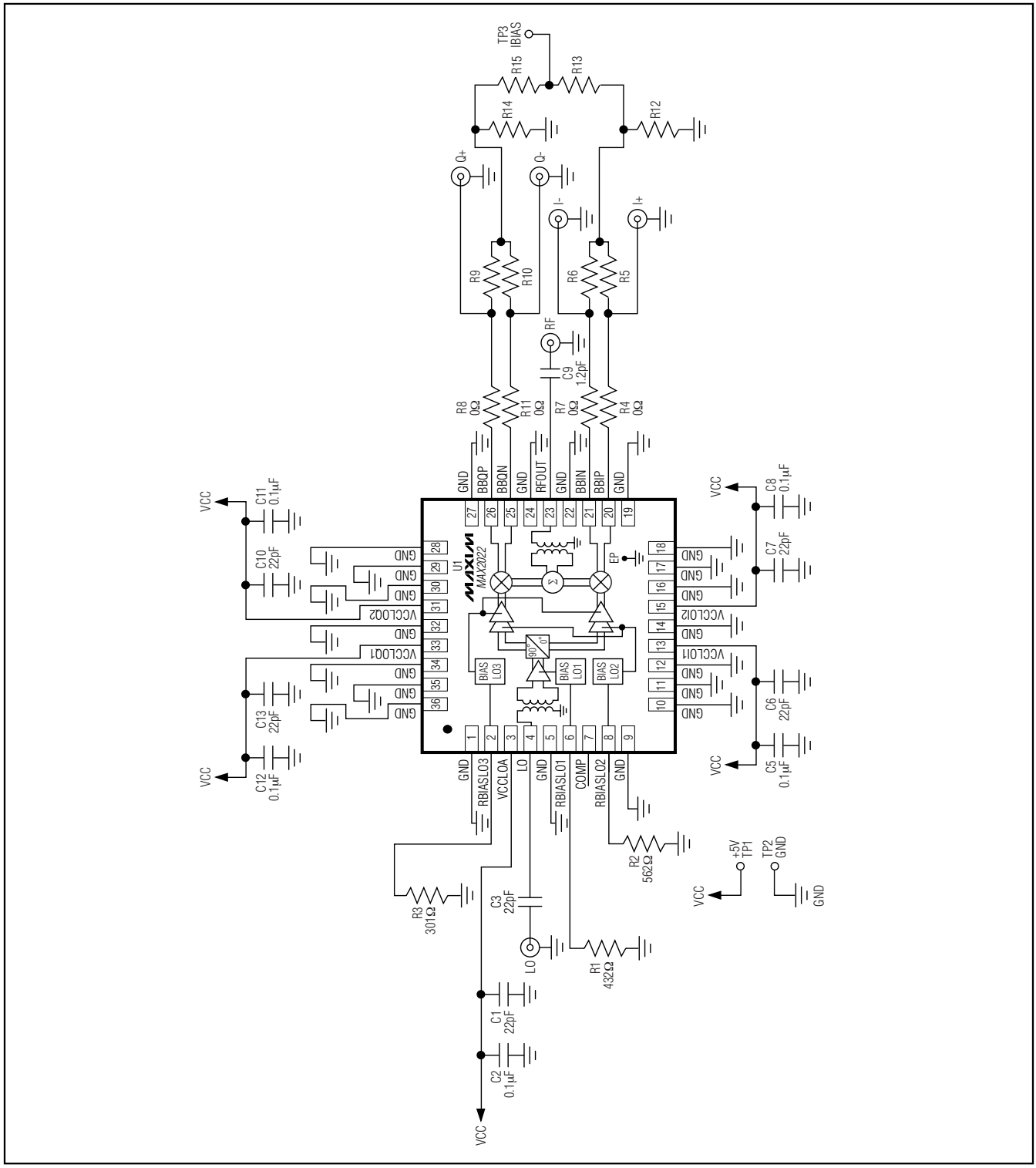


Figure 3. MAX2022 EV Kit Schematic

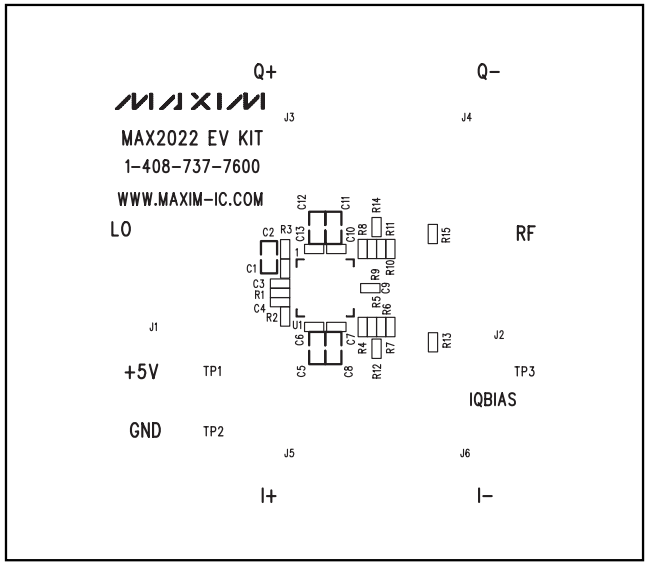


Figure 4. MAX2022 EV Kit PCB Layout—Top Silkscreen

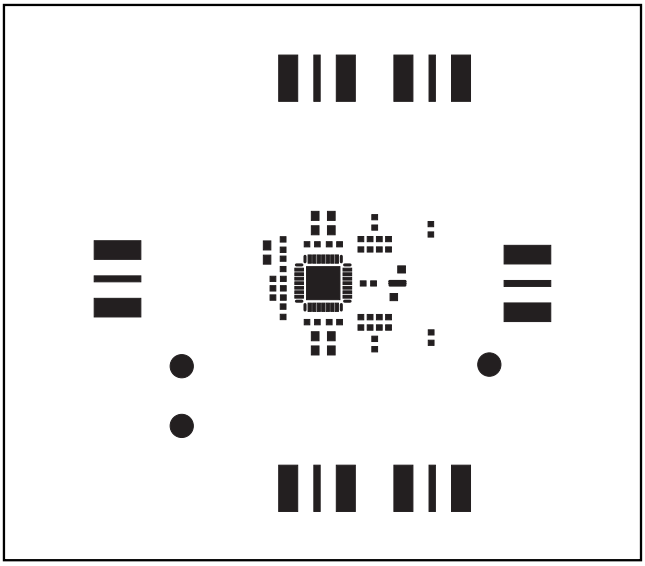


Figure 5. MAX2022 EV Kit PCB Layout—Top Soldermask

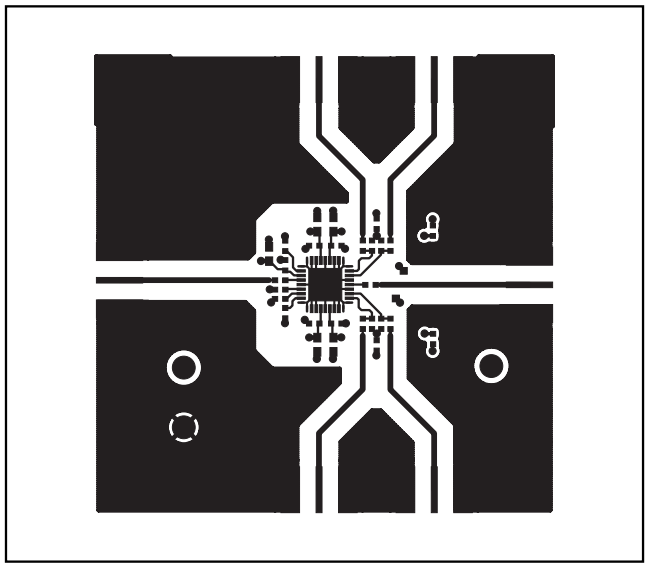


Figure 6. MAX2022 EV Kit PCB Layout—Top Layer Metal

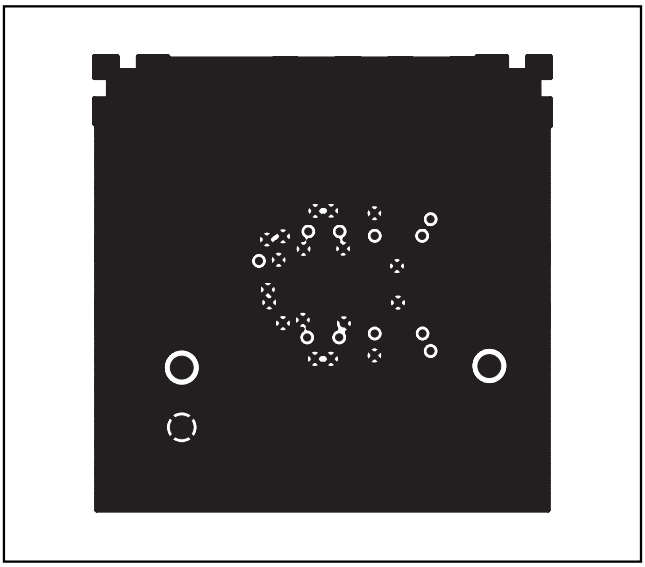


Figure 7. MAX2022 EV Kit PCB Layout—Inner Layer 2 (GND)

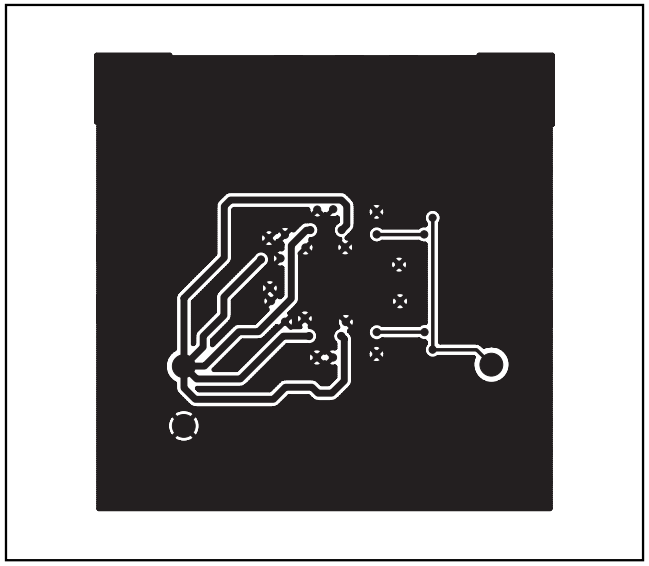


Figure 8. MAX2022 EV Kit PCB Layout—Inner Layer 3 (Routes)

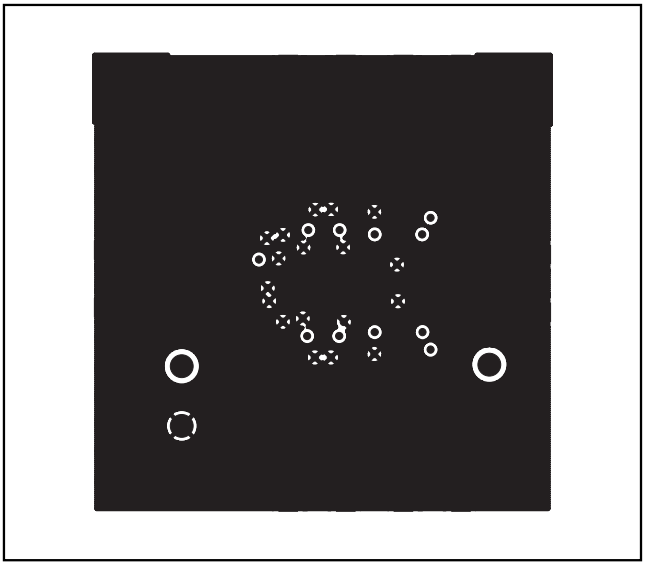


Figure 9. MAX2022 EV Kit PCB Layout—Bottom Layer (Metal)

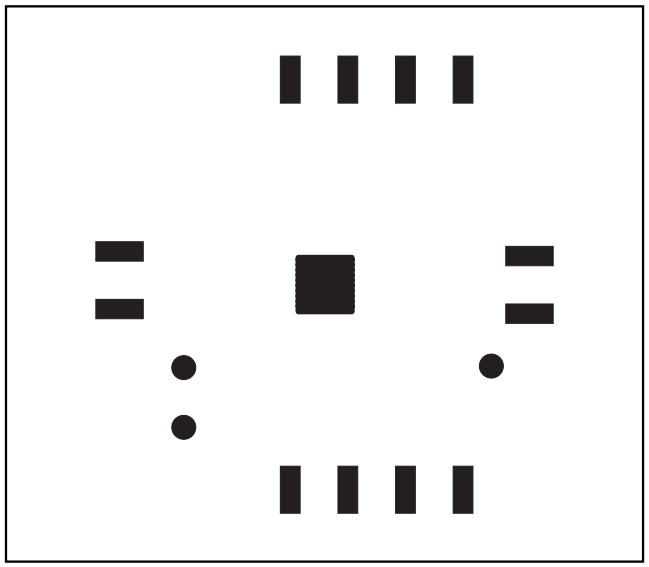


Figure 10. MAX2022 EV Kit PCB Layout—Bottom Soldermask

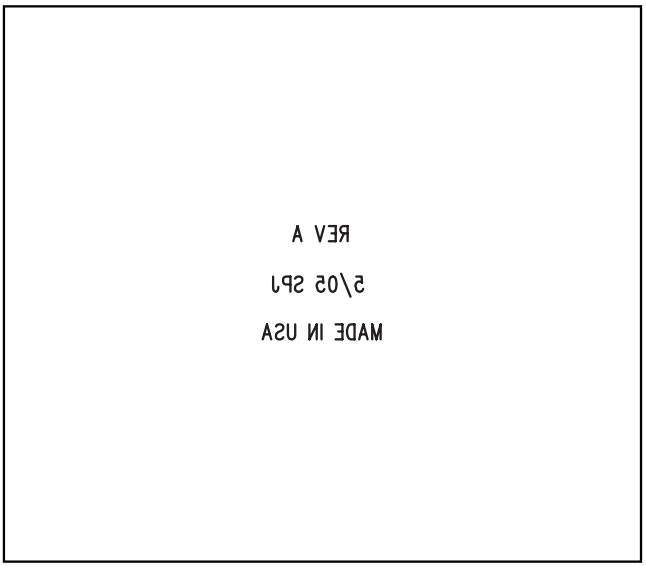


Figure 11. MAX2022 EV Kit PCB Layout—Bottom Silkscreen

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